

### Features

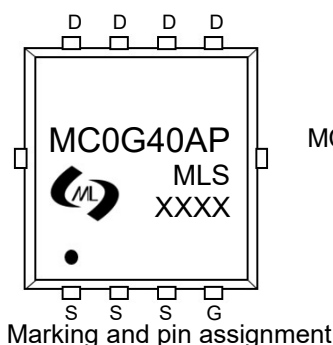
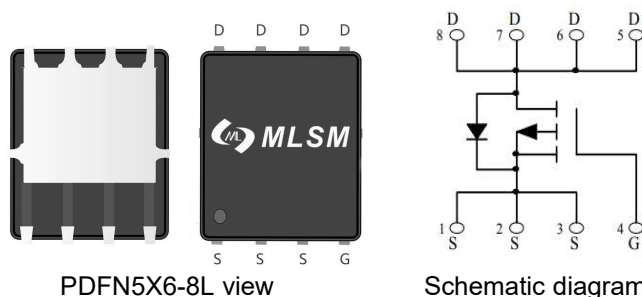
- High density cell design for ultra low  $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

### Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
|----------|------------------|-----------|
| -60V     | 35mΩ@-10V        | -10A      |
|          | 50mΩ@-4.5V       |           |

### Application

- PWM applications
- Power management
- Load switch



MC0G40AP: Device code  
 XXXX : Code



Halogen-Free

### Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

### Common Ratings ( $T_C=25^{\circ}\text{C}$ Unless Otherwise Noted)

|           |                                  |                                 |                    |
|-----------|----------------------------------|---------------------------------|--------------------|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | -60                             | V                  |
| $V_{GS}$  | Gate-Source Voltage              | $\pm 20$                        | V                  |
| $T_J$     | Maximum Junction Temperature     | 150                             | $^{\circ}\text{C}$ |
| $T_{STG}$ | Storage Temperature Range        | -55 to 150                      | $^{\circ}\text{C}$ |
| $I_S$     | Diode Continuous Forward Current | $T_C=25^{\circ}\text{C}$<br>-40 | A                  |

### Mounted on Large Heat Sink

|                 |                                        |                                  |                      |
|-----------------|----------------------------------------|----------------------------------|----------------------|
| $I_{DM}$        | Pulse Drain Current Tested             | $T_C=25^{\circ}\text{C}$<br>-160 | A                    |
| $I_D$           | Continuous Drain Current               | $T_C=25^{\circ}\text{C}$<br>-40  | A                    |
| $P_D$           | Maximum Power Dissipation              | $T_C=25^{\circ}\text{C}$<br>25   | W                    |
| $R_{\theta JA}$ | Thermal Resistance Junction-to-Ambient | 315                              | $^{\circ}\text{C/W}$ |

### Ordering Information (Example)

| Type     | Package    | Marking  | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|----------|------------|----------|----------------------|-------------------------|----------------------------|---------------|
| MC0G40AP | PDFN5X6-8L | MC0G40AP | 5,000                | 10,000                  | 70,000                     | 13"reel       |

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

| Symbol                                                                               | Parameter                        | Condition                                                                              | Min  | Typ  | Max  | Unit |
|--------------------------------------------------------------------------------------|----------------------------------|----------------------------------------------------------------------------------------|------|------|------|------|
| Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)  |                                  |                                                                                        |      |      |      |      |
| BV <sub>(BR)DSS</sub>                                                                | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA                                            | -60  | –    | –    | V    |
| I <sub>DSS</sub>                                                                     | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V                                             | --   | --   | -1   | μA   |
| I <sub>GSS</sub>                                                                     | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V                                             | --   | --   | ±100 | nA   |
| V <sub>GS(th)</sub>                                                                  | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA                              | -1.0 | -1.8 | -2.5 | V    |
| R <sub>DS(on)</sub>                                                                  | Drain-Source On-State Resistance | V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A                                            | --   | 25   | 35   | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A                                           | --   | 30   | 45   | mΩ   |
| Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated) |                                  |                                                                                        |      |      |      |      |
| C <sub>ISS</sub>                                                                     | Input Capacitance                | V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHz                                     | –    | 3880 | –    | pF   |
| C <sub>OSS</sub>                                                                     | Output Capacitance               |                                                                                        | –    | 169  | –    | pF   |
| C <sub>RSS</sub>                                                                     | Reverse Transfer Capacitance     |                                                                                        | –    | 138  | –    | pF   |
| Switching Characteristics                                                            |                                  |                                                                                        |      |      |      |      |
| Q <sub>g</sub>                                                                       | Total Gate Charge                | V <sub>DS</sub> =-30V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V                     | –    | 111  | –    | nC   |
| Q <sub>gs</sub>                                                                      | Gate Source Charge               |                                                                                        | –    | 25   | –    | nC   |
| Q <sub>gd</sub>                                                                      | Gate Drain Charge                |                                                                                        | –    | 15.5 | –    | nC   |
| t <sub>d(on)</sub>                                                                   | Turn-on Delay Time               | V <sub>DD</sub> =-10V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω | –    | 20   | –    | nS   |
| t <sub>r</sub>                                                                       | Turn-on Rise Time                |                                                                                        | –    | 25   | –    | nS   |
| t <sub>d(off)</sub>                                                                  | Turn-Off Delay Time              |                                                                                        | –    | 71   | –    | nS   |
| t <sub>f</sub>                                                                       | Turn-Off Fall Time               |                                                                                        | –    | 30   | –    | nS   |
| Source- Drain Diode Characteristics                                                  |                                  |                                                                                        |      |      |      |      |
| V <sub>SD</sub>                                                                      | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =-10A                                             | –    | –    | -1.2 | V    |

## Typical Operating Characteristics

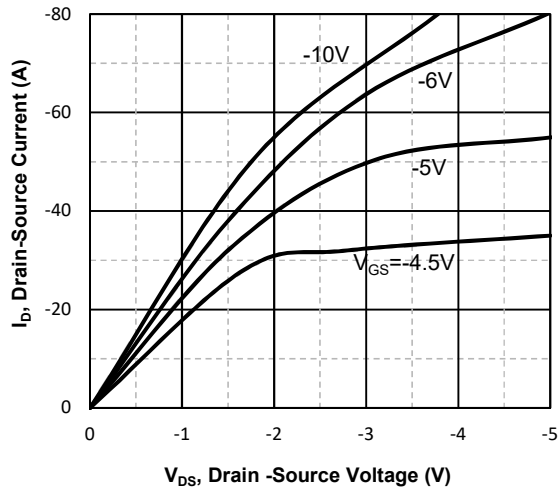


Fig1. Typical Output Characteristics

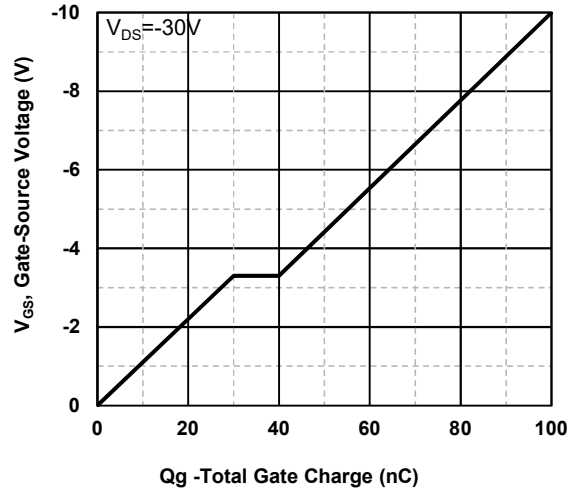


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

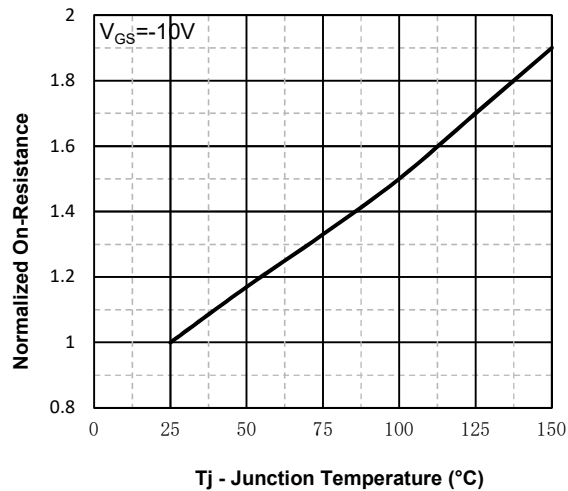


Fig3. Normalized On-Resistance Vs. Temperature

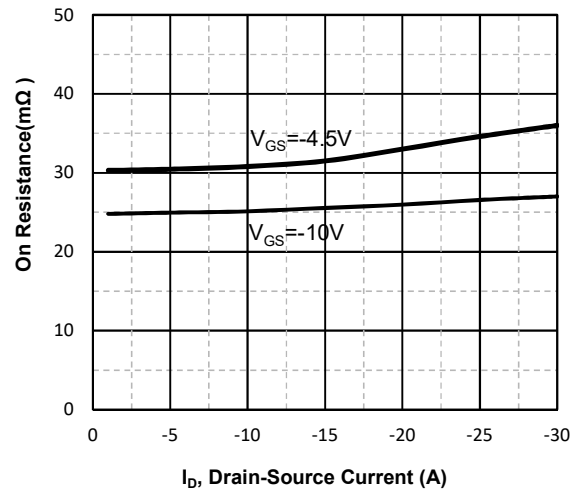


Fig4. Drain-Source on Resistance Vs. Drain-Source Current

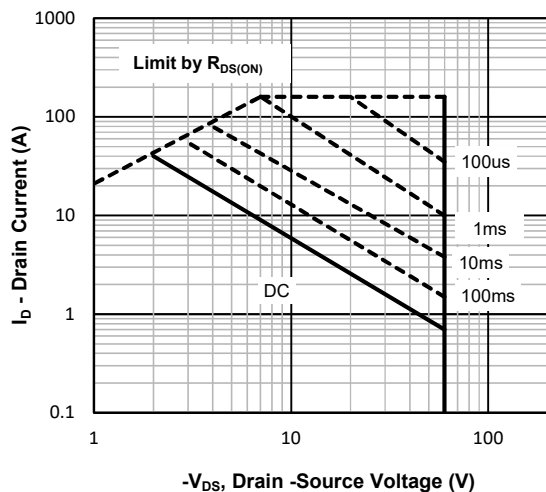


Fig5. Maximum Safe Operating Area

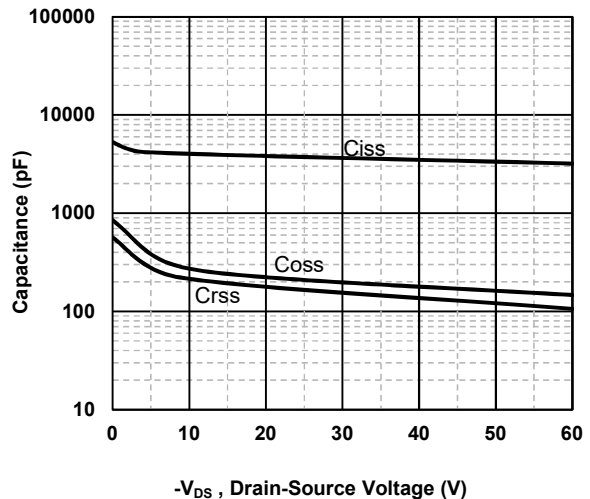
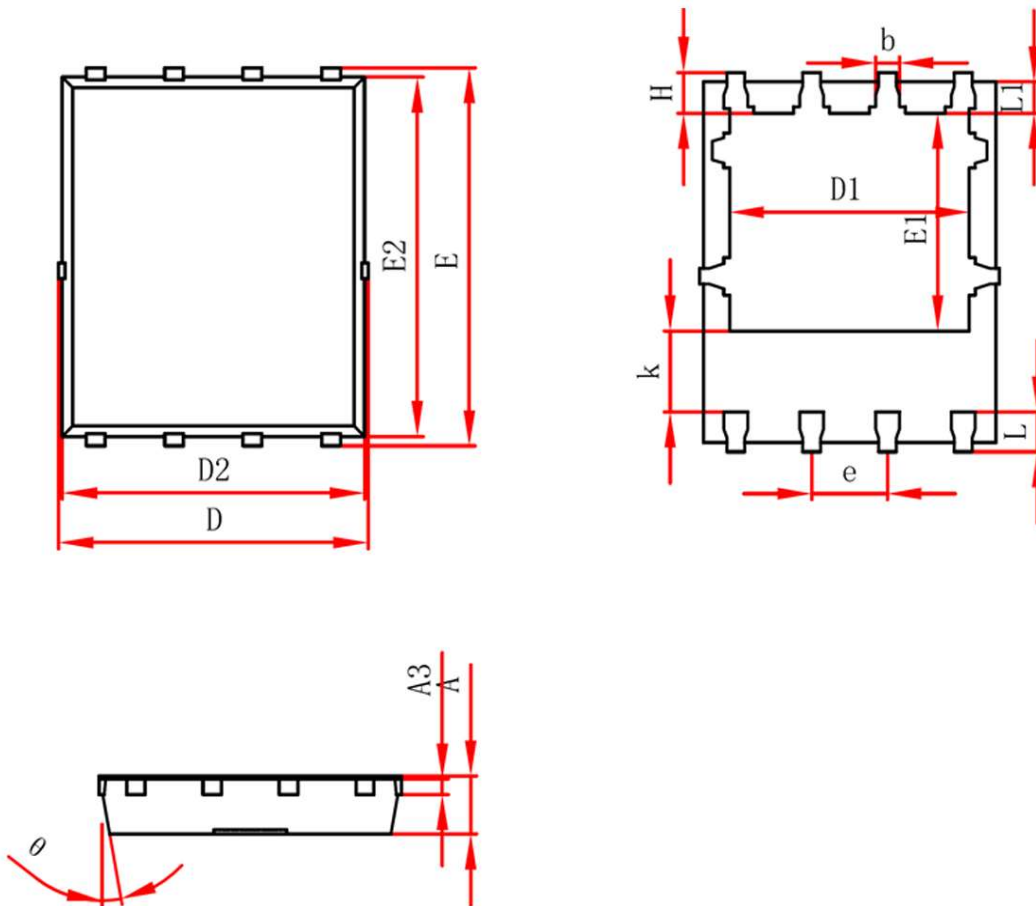


Fig6 Typical Capacitance Vs. Drain-Source Voltage

## PDFN5X6-8L Package information



| Symbol | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 0.950                         | 1.050 | 0.035                | 0.039 |
| A3     | 0.254REF.                     |       | 0.010REF.            |       |
| D      | 4.950                         | 5.050 | 0.196                | 0.200 |
| E      | 5.950                         | 6.050 | 0.235                | 0.239 |
| D1     | 4.026                         | 4.126 | 0.159                | 0.163 |
| E1     | 3.510                         | 3.610 | 0.139                | 0.143 |
| D2     | 4.850                         | 4.950 | 0.192                | 0.196 |
| E2     | 5.700                         | 5.800 | 0.225                | 0.229 |
| k      | 1.190                         | 1.390 | 0.047                | 0.055 |
| b      | 0.300                         | 0.400 | 0.012                | 0.016 |
| e      | 1.270TYP.                     |       | 0.050TYP.            |       |
| L      | 0.559                         | 0.711 | 0.022                | 0.028 |
| L1     | 0.424                         | 0.576 | 0.017                | 0.023 |
| H      | 0.574                         | 0.726 | 0.023                | 0.029 |
| θ      | 10°                           | 12°   | 10°                  | 12°   |